## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

**PEMH13**; **PUMH13** NPN/NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 47 kΩ

Product data sheet Supersedes data of 2003 Nov 07 2004 Apr 14



# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

PEMH13; PUMH13

#### **FEATURES**

- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- · Reduces pick and place costs.

#### **APPLICATIONS**

- · Low current peripheral driver
- Replacement of general purpose transistors in digital applications
- . Control of IC inputs.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
TR1	NPN	_	_	_
TR2	NPN	_	_	_
R1	bias resistor	4.7	_	kΩ
R2	bias resistor	47	=	kΩ

#### **DESCRIPTION**

NPN/NPN resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

#### PRODUCT OVERVIEW

TYPE NUMBER	PACK	AGE	MARKING CODE	PNP/PNP	NPN/PNP
TIFE NOWIBER	PHILIPS	EIAJ	WARKING CODE	COMPLEMENT	COMPLEMENT
PEMH13	SOT666	-	21	PEMB13	PEMD13
PUMH13	SOT363	SC-88	H0* <sup>(1)</sup>	PUMB13	PUMD13

#### Note

- \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TIPE NOWIBER	SIMPLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION		
PEMH13	6 5 4	1	emitter TR1		
PUMH13		2	base TR1		
	R1 R2	3	collector TR2		
	TR2	4	emitter TR2		
	TR1 R2 R1	5	base TR2		
		6	collector TR1		
	1 2 3				
	· wncoou				

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#### **ORDERING INFORMATION**

TYPE NUMBER		PACKAGE				
NAME		DESCRIPTION	VERSION			
PEMH13	<ul> <li>plastic surface mounted package; 6 leads</li> </ul>		SOT666			
PUMH13	<ul> <li>plastic surface mounted package; 6 leads</li> </ul>		SOT363			

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transis	tor			<b>-</b>	-
$V_{CBO}$	collector-base voltage	open emitter	_	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
Vı	input voltage positive		_	+30	V
	negative		_	<b>-</b> 5	V
I <sub>O</sub>	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT363	note 1	_	200	mW
	SOT666	notes 1 and 2	_	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C
Per device					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT363	note 1	_	300	mW
	SOT666	notes 1 and 2	_	300	mW

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#### **Notes**

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

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# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per transis	tor			
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> ≤ 25 °C		
	SOT363	note 1	625	K/W
	SOT666	notes 1 and 2	625	K/W
Per device				
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		T <sub>amb</sub> ≤ 25 °C		
	SOT363	note 1	416	K/W
	SOT666	notes 1 and 2	416	K/W

#### **Notes**

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Per transis	Per transistor							
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A	_	_	100	nA		
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A	_	_	1	μΑ		
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ		
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	_	_	170	μΑ		
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	100	_	_			
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$	_	_	100	mV		
$V_{i(off)}$	input-off voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	_	0.6	0.5	V		
$V_{i(on)}$	input-on voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 5 \text{ mA}$	1.3	0.9	_	V		
R1	input resistor		3.3	4.7	6.1	kΩ		
<u>R2</u> R1	resistor ratio		8	10	12			
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	_	2.5	pF		

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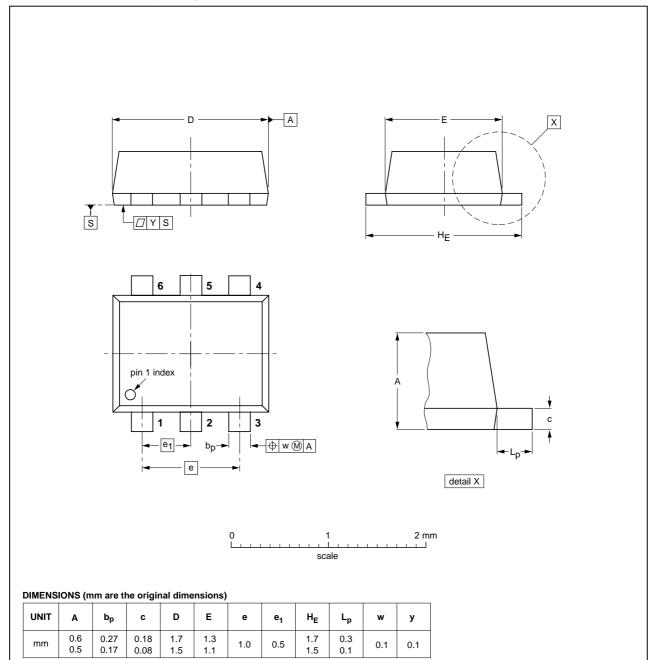
# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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#### **PACKAGE OUTLINES**

### Plastic surface-mounted package; 6 leads

SOT666



OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT666					<del>-04-11-08</del> 06-03-16	

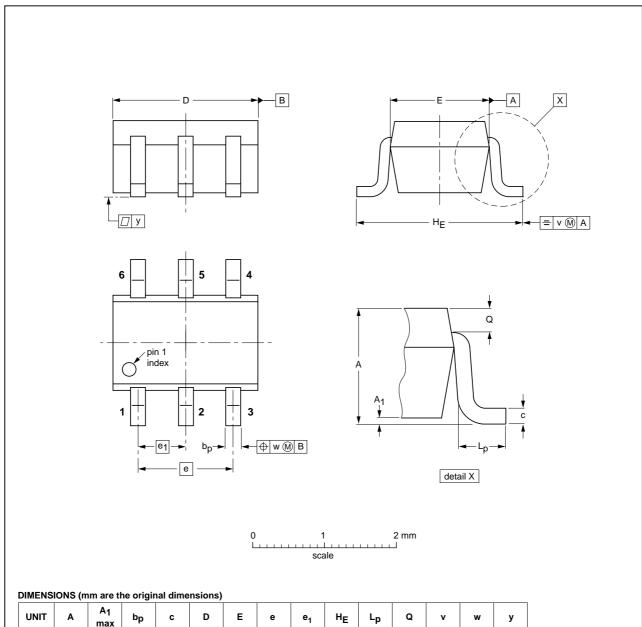
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# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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### Plastic surface-mounted package; 6 leads

**SOT363** 



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT363			SC-88			<del>-04-11-08</del> 

0.65

0.45

0.15

0.25

0.2

0.2

0.1

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0.25

0.10

1.35

1.3

1.1

0.1

mm

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

- 1. Please consult the most recently issued document before initiating or completing a design.
- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

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